

Product Summary

BV _{DSS}	RDS(ON) Max	Package	ID TA = +25°C
-30V	25mΩ @V _{GS} = -10V	SO-8	-6.0A
-300	38mΩ @Vgs = -4.5V	50-6	-4.7A

Description

This new generation MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- **DC-DC** Converters
- **Power Management Functions**
- Load Switch

Features

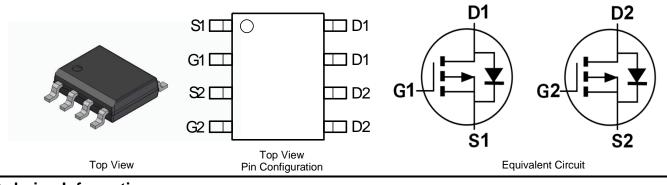
- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at https://www.diodes.com/products/automotive/automotive-

products/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.074 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3028LSD-13	SO-8	2,500/Tape & Reel

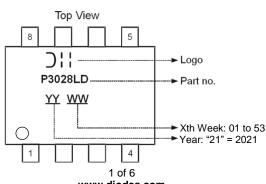
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Notes:

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Drain-Source Voltage	Vdss	-30	V			
Gate-Source Voltage	V _{GSS}	±20	V			
Continuous Drain Current (Note 5) \/ 10\/	Steady State	T _A = +25°C T _A = +70°C	ID	-6 -4.7	А	
Continuous Drain Current (Note 5) V_{GS} = 10V	t < 10s	T _A = +25°C T _A = +70°C	ID	-7.4 -5.8	A	
Maximum Body Diode Forward Current (Note 6)			ls	-2.5	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Idм	-30	А	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Dawar Dissinction (Nata 5)	T _A = +25°C	D-	1.3	W
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.8	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Roja	102	°C/W
	t < 10s	ROJA	61	
Total Dower Dissinction (Note 6)	T _A = +25°C	PD	1.7	W
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.1	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Dave	75	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	Roja	50	
Thermal Resistance, Junction to Case (Note 6)		Røjc	14.5	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			1	1		
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS			-1	μA	$V_{DS} = -30V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	-1	—	-3	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Design	_	20	25	mΩ	$V_{GS} = -10V, I_D = -7A$
	RDS(ON)	—	29	38	11152	V _{GS} = -4.5V, I _D = -5.5A
Forward Transfer Admittance	Y _{fs}	—	11	—	S	V _{DS} = -5V, I _D = -7A
Diode Forward Voltage	Vsd	—	0.7	1.2	V	V _{GS} = 0V, I _S = -2.1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	1241	—		V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	Coss	—	147	—	pF	
Reverse Transfer Capacitance	Crss	—	110	—		
Gate Resistance	Rg	—	15	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge ($V_{GS} = -4.5V$)	Qg	—	11	—		
Total Gate Charge (V _{GS} = -10V)	Qg	—	22	—	nC	
Gate-Source Charge	Qgs	—	3.5	—	nc	V _{DS} = -15V, I _D = -7A
Gate-Drain Charge	Q _{gd}	—	4.7	—		
Turn-On Delay Time	tD(ON)	_	9.7	—		
Turn-On Rise Time	t _R	_	17.1	—	ns	$V_{GS} = -10V$, $V_{DD} = -15V$, $R_{GEN} = 6\Omega$,
Turn-Off Delay Time	t _{D(OFF)}	_	60.5	—	115	I _D = -7A
Turn-Off Fall Time	tF	_	40.4	—		

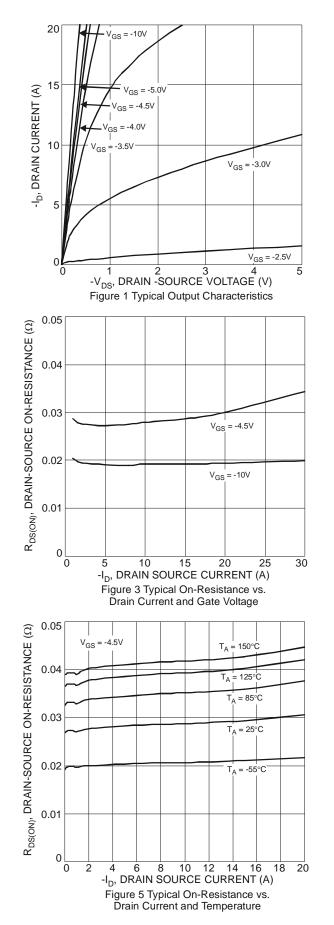
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

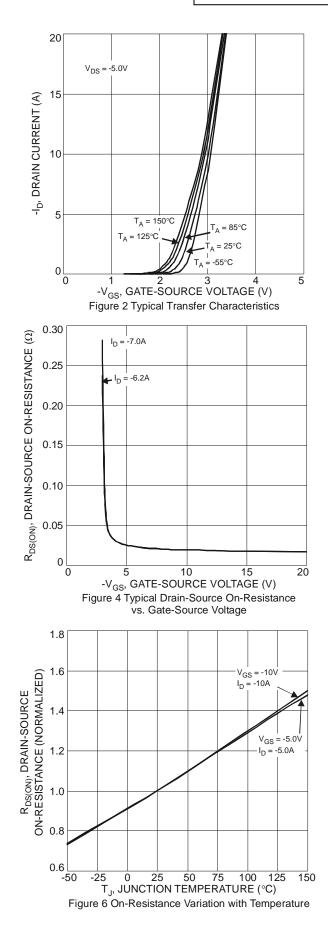
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

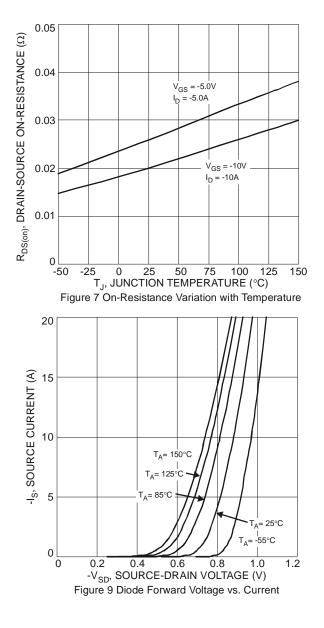
8. Guaranteed by design. Not subject to product testing.

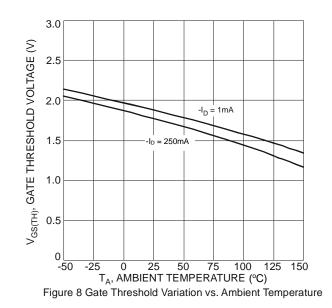














Тур

1.45

0.15

0.40

0.20

4.90

6.00

3.85

3.90

1.27

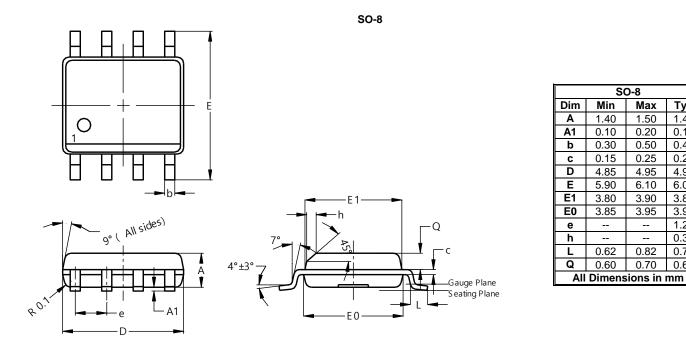
0.35

0.72

0.65

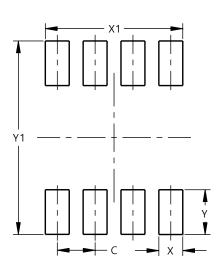
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8

Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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